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#### **FDT459N N-Channel Enhancement Mode Field Effect Transistor**

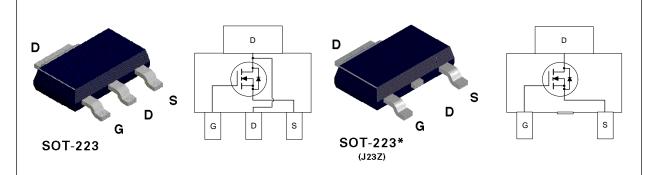
#### **General Description**

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance, provide superior switching performance. These products are well suited to low voltage, low current applications such as notebook computer power management, battery powered circuits, and DC motor control.

#### Features

- 6.5 A, 30 V.  $R_{DS(ON)} = 0.035\Omega @ V_{GS} = 10 V$  $R_{DS(ON)} = 0.055 \ \Omega \ @ V_{GS} = 4.5 \ V.$
- High density cell design for extremely low R<sub>DS(ON)</sub>.
- High power and current handling capability in a widely used surface mount package.





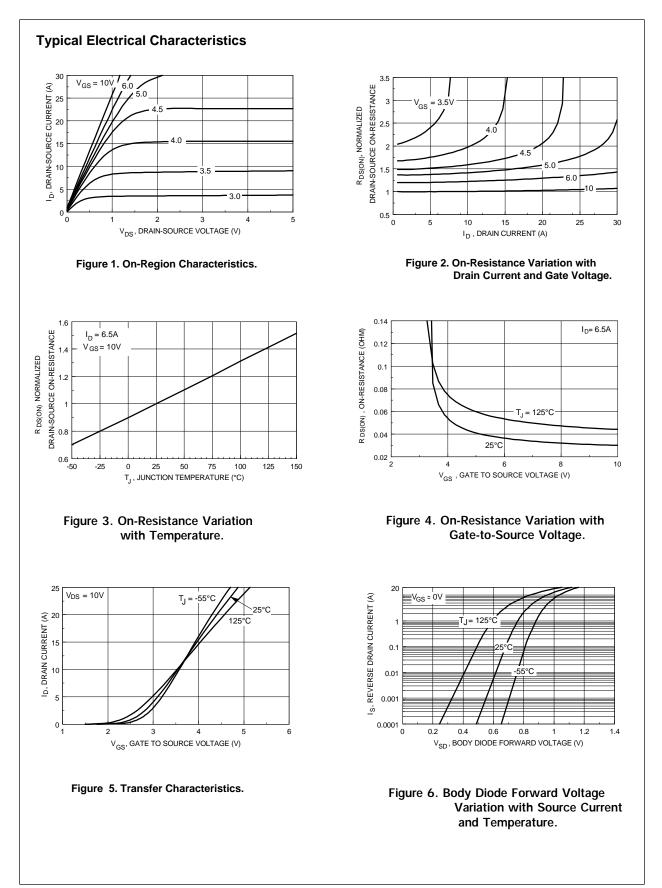
#### **Absolute Maximum Ratings** $T_{A} = 25^{\circ}C$ unless otherwise noted

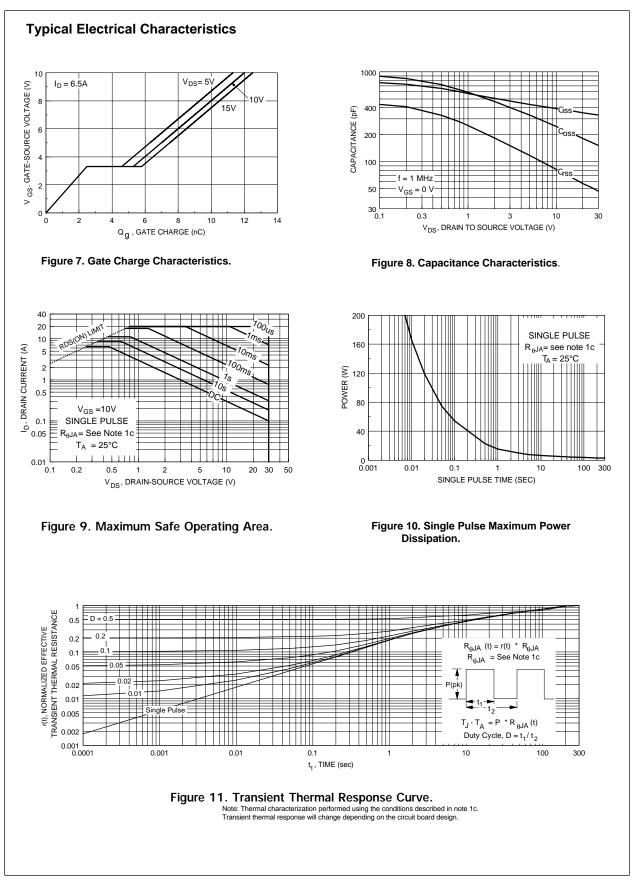
Symbol	Parameter		FDT459N	Units
V <sub>DSS</sub>	Drain-Source Voltage		30	V
V <sub>GSS</sub>	Gate-Source Voltage - Continuous		±20	V
D	Maximum Drain Current - Continuous	(Note 1a)	6.5	A
	- Pulsed		20	
P <sub>D</sub>	Maximum Power Dissipation	(Note 1a)	3	W
		(Note 1b)	1.3	
		(Note 1c)	1.1	
Г <sub>J</sub> ,Т <sub>stg</sub>	Operating and Storage Temperature F	Range	-55 to 150	°C
THERMA	L CHARACTERISTICS			
R <sub>eja</sub>	Thermal Resistance, Junction-to-Amb	ient (Note 1a)	42	°C/W
R <sub>ejc</sub>	Thermal Resistance, Junction-to-Cas	e (Note 1)	12	°C/W

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Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHARA	CTERISTICS	I				1	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		30			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm p}$ = 250 µA, Referenced to	o 25°C		33		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$				1	μA
200	_		T_=55°C			10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				100	nA
	Gate - Body Leakage, Reverse	$V_{gs} = -20 \text{ V}, V_{Ds} = 0 \text{ V}$				-100	nA
	CTERISTICS (Note 2)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		1	1.6	2	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp.Coefficient	$I_{\rm D}$ = 250 µA, Referenced to	o 25 ℃		-4.2		mV/°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{\rm GS} = 10 \text{ V}, \ \text{I}_{\rm D} = 6.5 \text{ A}$			0.031	0.035	Ω
00(01)			T_=125°C		0.044	0.06	
		$V_{GS} = 4.5 \text{ V}, I_{D} = 5.5 \text{ A}$	5		0.046	0.055	-
D(ON)	On-State Drain Current	$V_{GS} = 10 \text{ V}, \text{ V}_{DS} = 5 \text{ V}$		20			А
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_{D} = 6.5 \text{ A}$			16		S
	HARACTERISTICS						
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 15 V, V_{GS} = 0 V,$ f = 1.0 MHz			365		pF
C <sub>oss</sub>	Output Capacitance				210		pF
C <sub>rss</sub>	Reverse Transfer Capacitance				70		pF
SWITCHING	CHARACTERISTICS (Note 2)						•
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DD} = 15 V, I_{D} = 1 A,$			5.2	11	ns
t,	Turn - On Rise Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$			8.2	16	ns
t <sub>D(off)</sub>	Turn - Off Delay Time	_			6	12	ns
t <sub>r</sub>	Turn - Off Fall Time				16	26	ns
Q <sub>g</sub>	Total Gate Charge	$V_{\rm DS} = 10 \text{ V}, \ \text{I}_{\rm D} = 6.5 \text{ A},$			12	17	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V			2.2		nC
Q <sub>gd</sub>	Gate-Drain Charge	7			3		nC
DRAIN-SOUI	RCE DIODE CHARACTERISTICS AND MAX	IMUM RATINGS				-	_
l <sub>s</sub>	Maximum Continuous Drain-Source Diode Fo					2.5	А
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 2.5 A$ (Note	2)		0.8	1.2	V
Notes: 1. R <sub>e<sup>JA</sup></sub> is the sum design while R <sub>e</sub>	of the junction-to-case and case-to-ambient thermal resistance where the user's board design. Sing the board layouts shown below on FR-4 PCB in a still air environment of the still air envi	ronment: Ψ		ų L	0 □ c. 110°0 in² pad	pins. R <sub>ev</sub> cis g C/W when me of 2oz Cu.	





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